

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE40H25LL uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

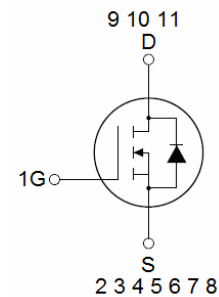
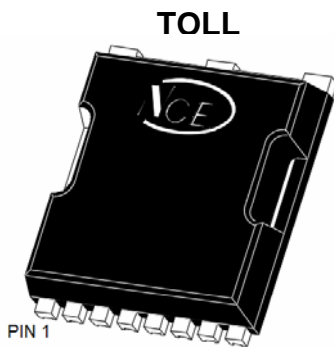
Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

General Features

- $V_{DS} = 40V, I_D = 250A$
 $R_{DS(ON)} < 2.0m\Omega @ V_{GS}=10V$
- High density cell design for ultra low R_{dson}
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

100% UIS TESTED!
100% ΔV_{ds} TESTED!



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE40H25LL	NCE40H25LL	TOLL	-	-	-

Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	250	A
Drain Current-Continuous($T_C=100^\circ C$)	$I_D(100^\circ C)$	177	A
Pulsed Drain Current	I_{DM}	1000	A
Maximum Power Dissipation	P_D	350	W
Derating factor		2.33	W/ $^\circ C$
Single pulse avalanche energy ^(Note 5)	E_{AS}	2500	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	$^\circ C$

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{\theta JC}$	0.43	$^\circ C/W$
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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

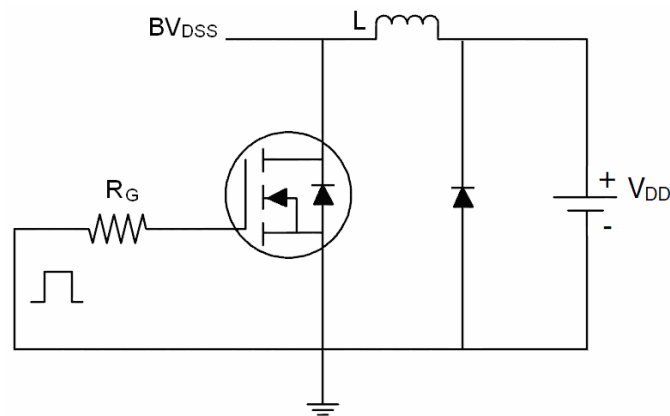
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	40		-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=40V, V_{GS}=0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.3	1.8	2.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=20A$	-	1.7	2.0	m Ω
Forward Transconductance	g_{FS}	$V_{DS}=5V, I_D=20A$	-	100	-	S
Dynamic Characteristics (Note 4)						
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V,$ $F=1.0\text{MHz}$	-	10331	-	PF
Output Capacitance	C_{oss}		-	1160	-	PF
Reverse Transfer Capacitance	C_{rss}		-	1045	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=30V, R_L=1.5\Omega,$ $R_G=2.5\Omega, V_{GS}=10V$	-	41	-	nS
Turn-on Rise Time	t_r		-	40	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	145	-	nS
Turn-Off Fall Time	t_f		-	65	-	nS
Total Gate Charge	Q_g	$I_D=20A, V_{DD}=20V, V_{GS}=10V$	-	239	-	nC
Gate-Source Charge	Q_{gs}		-	23.5	-	nC
Gate-Drain Charge	Q_{gd}		-	49.6	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	$V_{GS}=0V, I_S=20A$	-	0.85	1.2	V
Diode Forward Current (Note 2)	I_S		-	-	250	A
Reverse Recovery Time	t_{rr}	$T_J = 25^\circ\text{C}, I_F = 20A$ $di/dt = 100A/\mu s$ (Note 3)	-	55		nS
Reverse Recovery Charge	Q_{rr}		-	90		nC
Forward Turn-On Time	t_{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

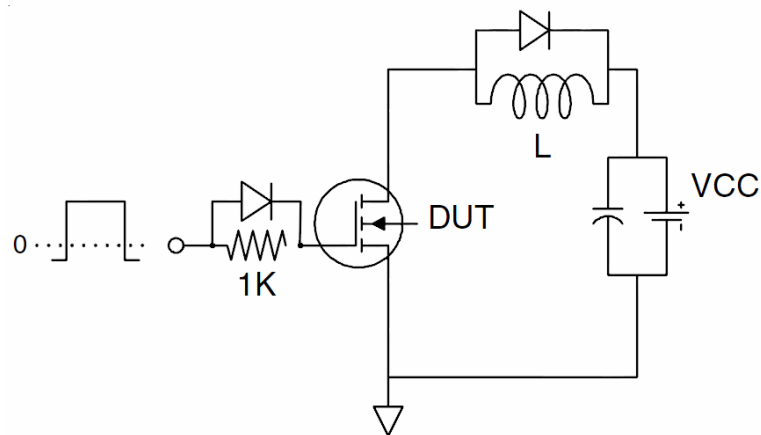
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production
5. EAS condition: $T_J=25^\circ\text{C}, V_{DD}=20V, V_G=10V, L=0.5\text{mH}, R_G=25\Omega$

Test circuit

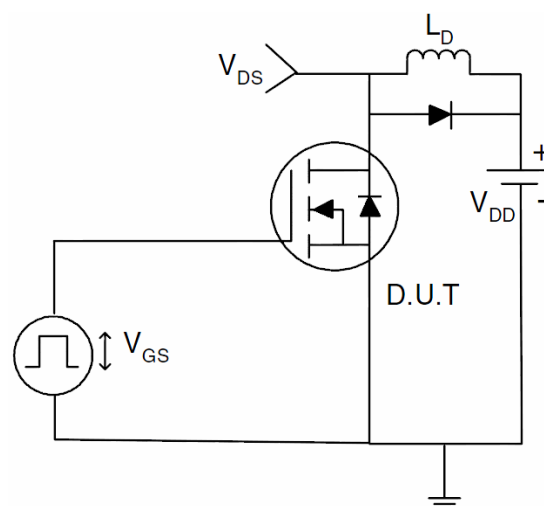
1) E_{AS} test Circuits



2) Gate charge test Circuit:



3) Switch Time Test Circuit:



Typical Electrical and Thermal Characteristics (Curves)

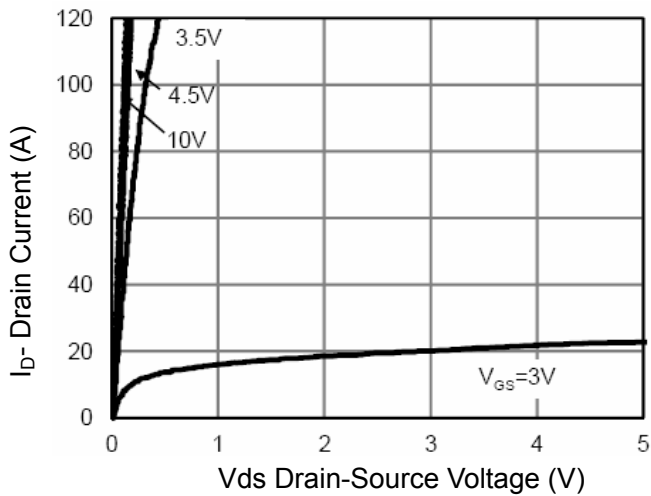


Figure 1 Output Characteristics

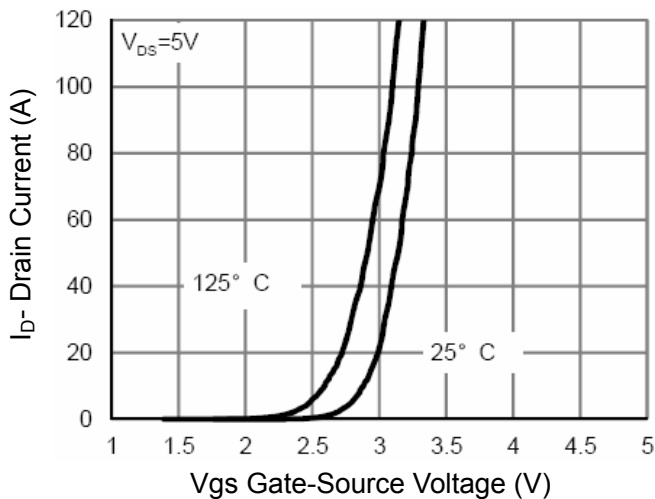


Figure 2 Transfer Characteristics

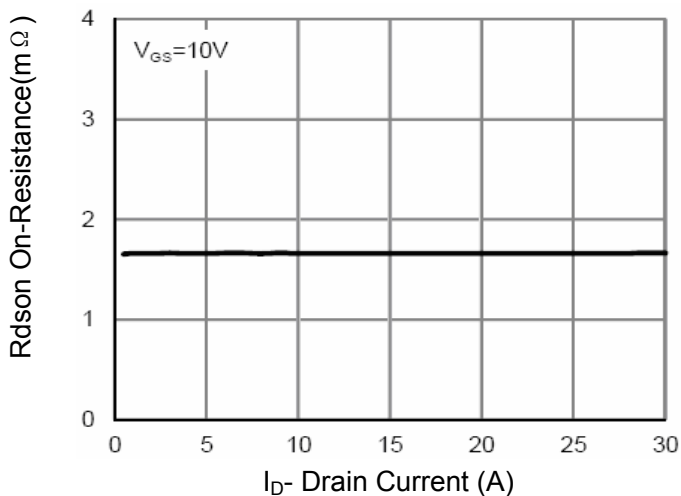


Figure 3 Rdson- Drain Current

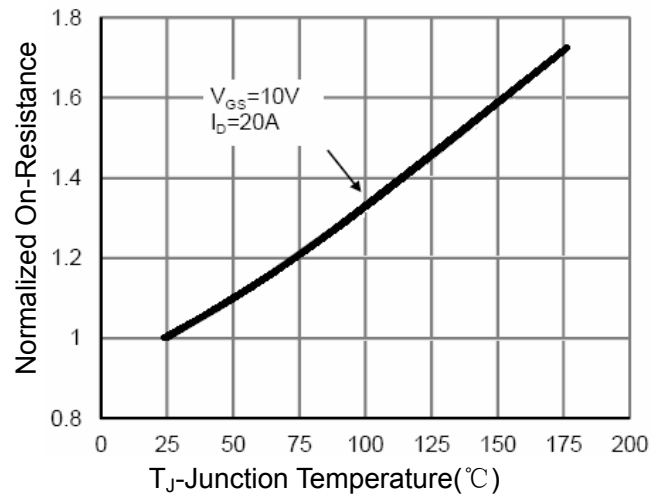


Figure 4 Rdson-Junction Temperature

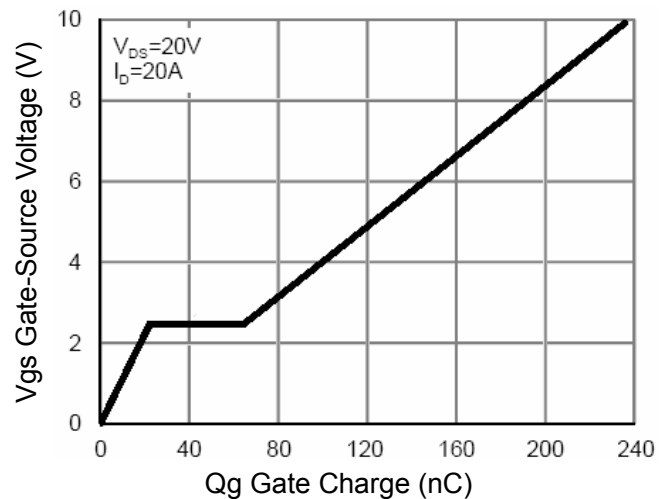


Figure 5 Gate Charge

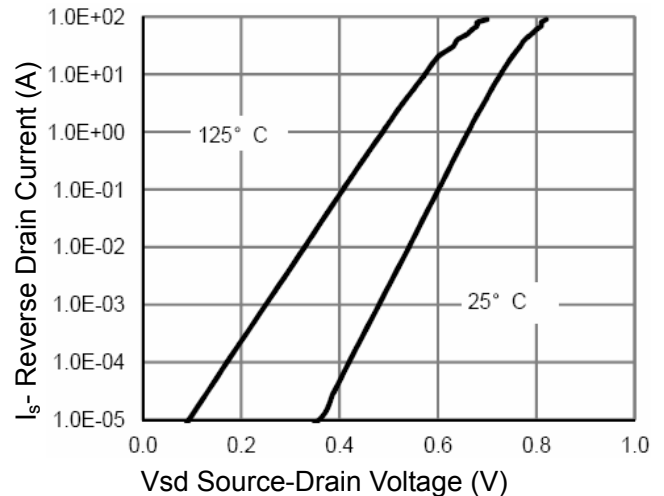


Figure 6 Source- Drain Diode Forward

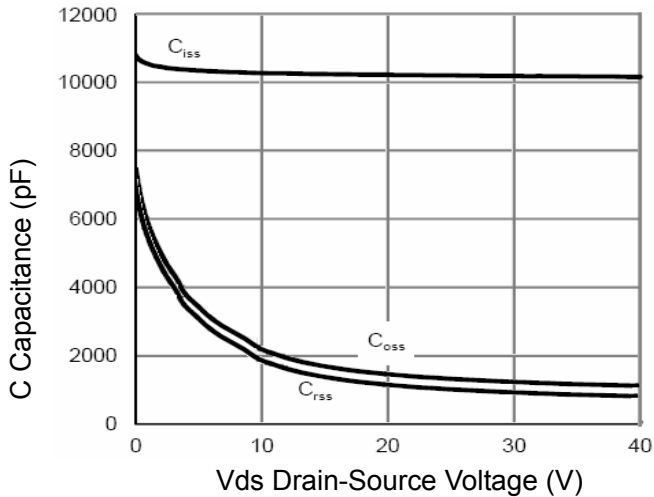


Figure 7 Capacitance vs Vds

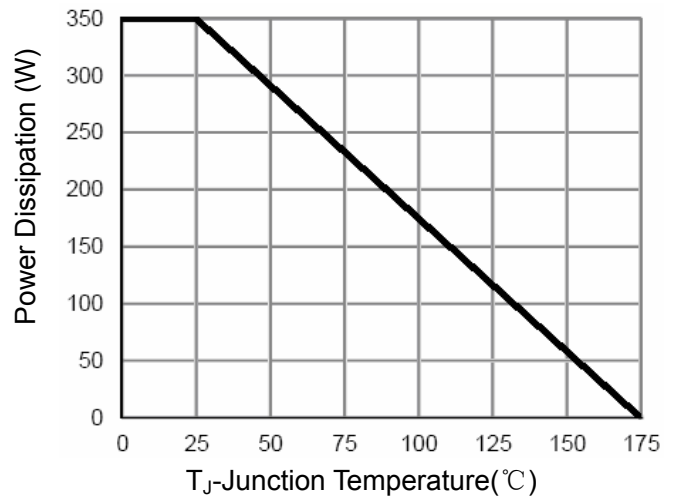


Figure 9 Power De-rating

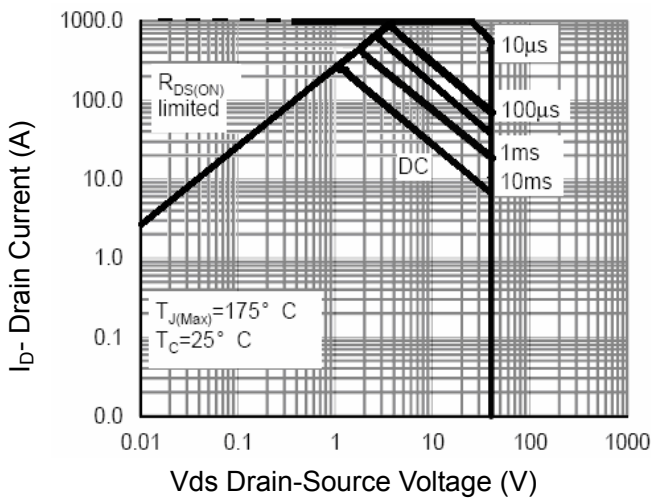


Figure 8 Safe Operation Area

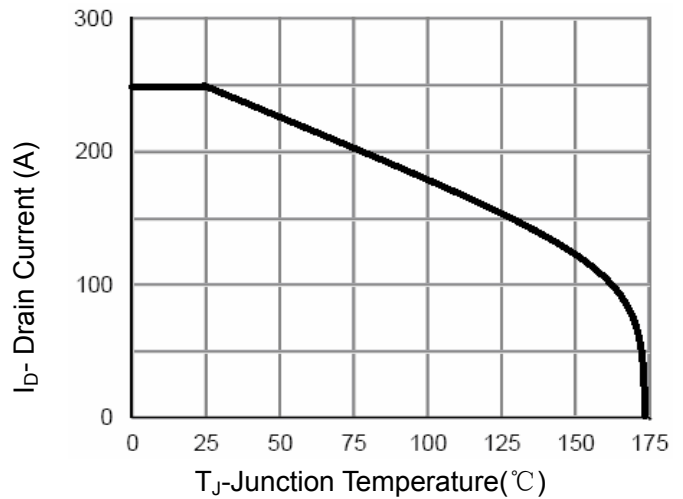


Figure 10 Current De-rating

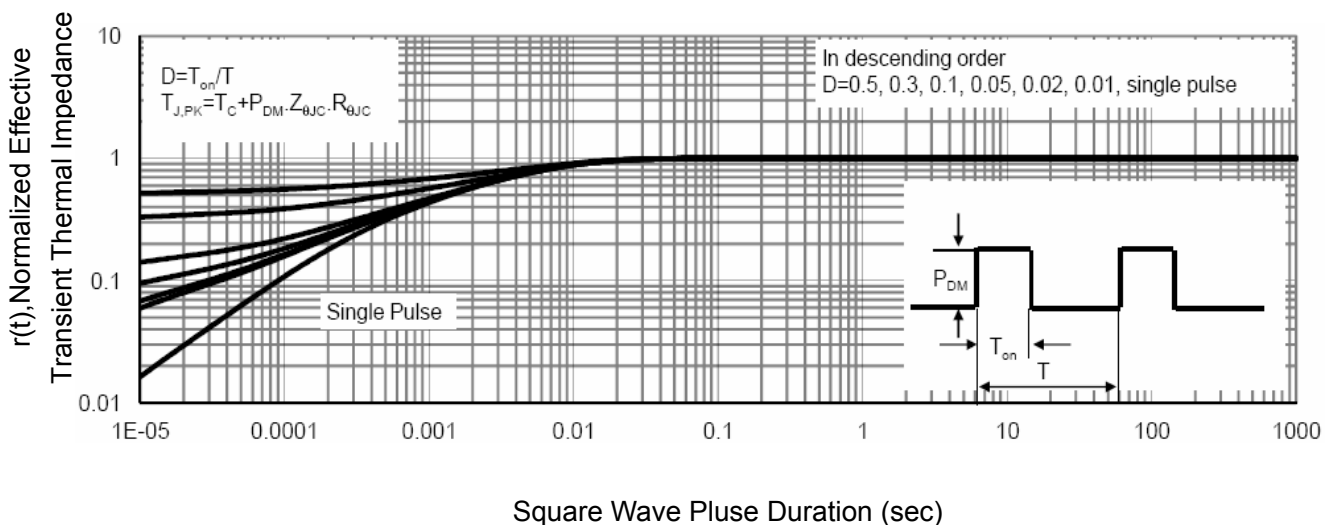
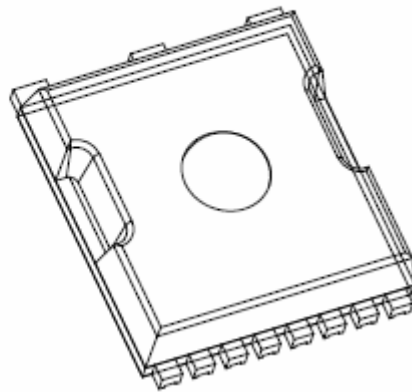
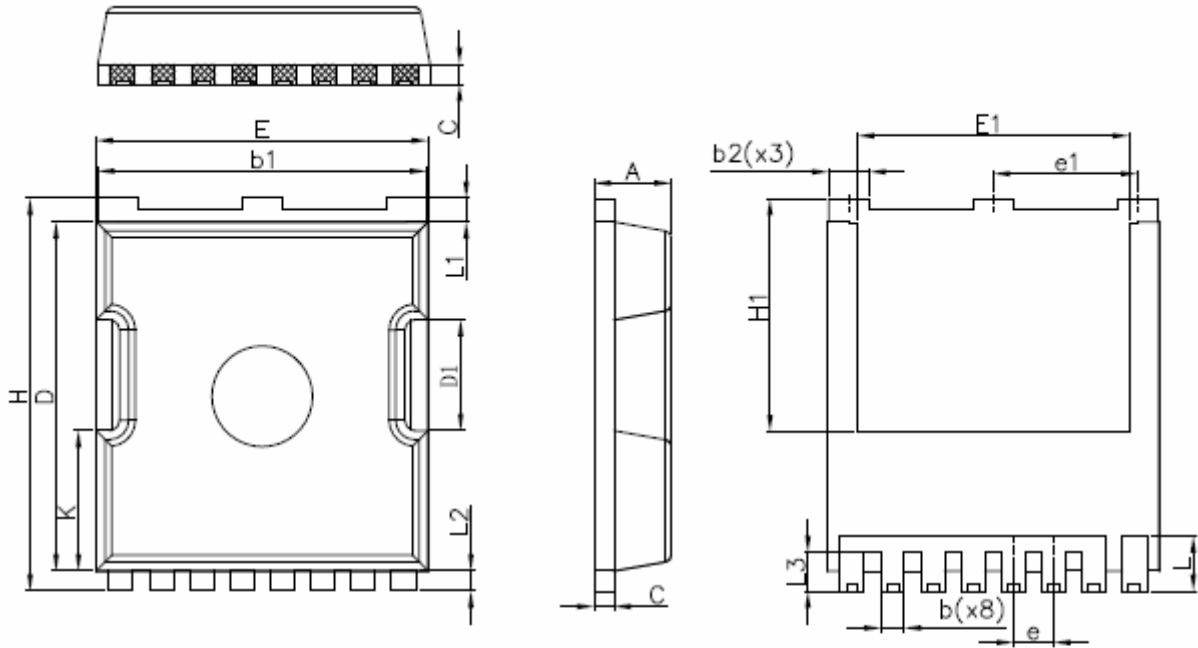


Figure 11 Normalized Maximum Transient Thermal Impedance

TOLL Package Information



TOLL-8L			
DIM.	MIN.	NOM.	MAX.
A	2.20	2.30	2.40
b	0.65	0.75	0.85
b1	9.70	9.80	9.90
b2	1.10	1.20	1.30
C	0.50	0.60	0.70
D	10.30	10.40	10.50
D1	3.15	3.30	3.45
E	9.70	9.90	10.10
E1	8.00	8.10	8.20
e	1.10	1.20	1.30
e1	4.20	4.30	4.40
H	11.60	11.70	11.80
H1	6.85	6.95	7.05
K	4.08	4.18	4.28
L	1.60	1.65	2.10
L1	0.60	0.70	0.80
L2	0.50	0.60	0.70
L3	1.05	1.20	1.30
All dimensions in millimeters			

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